

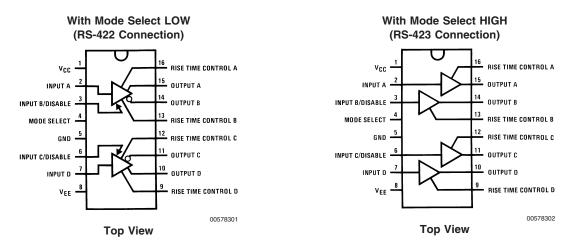
DS1691A/DS3691 (RS-422/RS-423) Line Drivers with TRI-STATE® Outputs General Description Features

The DS1691A/DS3691 are low power Schottky TTL line drivers designed to meet the requirements of EIA standards RS-422 and RS-423. They feature 4 buffered outputs with high source and sink current capability with internal short circuit protection. A mode control input provides a choice of operation either as 4 single-ended line drivers or 2 differential line drivers. A rise time control pin allows the use of an external capacitor to slow the rise time for suppression of near end crosstalk to other receivers in the cable. Rise time capacitors are primarily intended for waveshaping output signals in the single-ended driver mode. Multipoint applications in differential mode with waveshaping capacitors is not allowed.

With the mode select pin low, the DS1691A/DS3691 are dual-differential line drivers with TRI-STATE outputs. They feature $\pm 10V$ output common-mode range in TRI-STATE mode and 0V output unbalance when operated with $\pm 5V$ supply.

- Dual RS-422 line driver with mode pin low, or quad RS-423 line driver with mode pin high
- TRI-STATE outputs in RS-422 mode
- Short circuit protection for both source and sink outputs
- Outputs will not clamp line with power off or in TRI-STATE
- 100Ω transmission line drive capability
- Low I_{CC} and I_{EE} power consumption RS-422: I_{CC} = 9 mA/driver typ RS-423: I_{CC} = 4.5 mA/driver typ: I_{EE} = 2.5 mA/driver typ
- Low current PNP inputs compatible with TTL, MOS and CMOS
- Pin compatible with AM26LS30

Connection Diagrams



Ordering Information

Order Number	Package Type	NS Package Number					
DS3691M	SO Package	M16A					
DS3691N	Molded DIP	N16E					
For Complete Military Product Specifications, refer to the appropriate SMD or MDS.							
DS1691AJ/883	Ceramic DIP	J16A					

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Absolute Maximum Ratings (Note 2)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/ Distributors for availability and specifications.

Supply Voltage	
V _{CC}	7V
V _{EE}	-7V
Maximum Power Dissipation (Note 1) a	t 25°C
Cavity Package	1509 mW
Molded DIP Package	1476 mW
SO Package	1051 mW
Input Voltage	15V
Output Voltage (Power OFF)	±15V
Storage Temperature	–65°C to + 150°C
Lead Temperature	
(Soldering, 4 seconds)	260°C

Operating Co	nditions	;	
	Min	Max	Units
Supply Voltage			
DS1691A			
V _{CC}	4.5	5.5	V
V _{EE}	-4.5	-5.5	V
DS3691			
V _{CC}	4.75	5.25	V
V _{EE}	-4.75	-5.25	V
Temperature (T _A)			
DS1691A	-55	+125	°C

Note 1: Derate cavity package 10.1 mW/°C above 25°C; derate molded DIP package 11.9 mW/°C above 25°C. Derate SO package 8.41 mW/°C above 25°C.

0

+70

DS3691

°C

DC Electrical Characteristics (Notes 3, 4, 5, 6)

Symbol	Parameter	Cond	itions	Min	Тур	Max	Units
RS-422 CONNE	CTION, V _{EE} CONNECTION TO C	ROUND, MODE SELE	CT ≤ 0.8V				
V _{IH}	High Level Input Voltage			2			V
V _{IL}	Low Level Input Voltage					0.8	V
I _{IH}	High Level Input Current	V _{IN} = 2.4V			1	40	μA
		$V_{IN} \le 15V$			10	100	μA
I _{IL}	Low Level Input Current	$V_{IN} = 0.4V$	$V_{IN} = 0.4V$		-30	-200	μA
V _I	Input Clamp Voltage	I _{IN} = -12 mA				-1.5	V
Vo	Differential Output Voltage	R _L = ∞	$V_{IN} = 2V$		3.6	6.0	V
$\overline{V_O}$	V _{A,B}		$V_{IN} = 0.8V$		-3.6	-6.0	V
V _T	Differential Output Voltage	R _L = 100Ω	$V_{IN} = 2V$	2	2.4		V
$ \frac{\overline{V_o}}{\overline{V_T}} $	V _{A,B}	$V_{CC} \ge 4.75V$	$V_{IN} = 0.8V$	-2	-2.4		V
$V_{OS}, \overline{V_{OS}}$	Common-Mode Offset	R _L = 100Ω			2.5	3	V
	Voltage						
$ V_T - V_T $	Difference in Differential	R _L = 100Ω			0.05	0.4	V
	Output Voltage						
$ V_{OS} - \overline{V_{OS}} $	Difference in Common-	R _L = 100Ω			0.05	0.4	V
	Mode Offset Voltage						
V _{SS}	$ V_T - \overline{V_T} $	$R_{L} = 100\Omega, V_{CC} \ge 4.75V$		4.0	4.8		V
V _{CMR}	Output Voltage Common-	V _{DISABLE} = 2.4V		±10			V
	Mode Range						
I _{XA}	Output Leakage Current	$V_{\rm CC} = 0V$	$V_{CMR} = 10V$			100	μA
I _{XB}	Power OFF		$V_{CMR} = -10V$			-100	μA
I _{ox}	TRI-STATE Output Current	V _{CC} = Max	$V_{CMR} \le 10V$			100	μA
		$V_{EE} = 0V$ and $-5V$	$V_{CMR} \ge -10V$			-100	μA
I _{SA}	Output Short Circuit Current	$V_{IN} = 0.4V$	V _{OA} = 6V		80	150	mA
			$V_{OB} = 0V$		-80	-150	mA
I _{SB}	Output Short Circuit Current	V _{IN} = 2.4V	$V_{OA} = 0V$		-80	-150	mA
			V _{OB} = 6V		80	150	mA
I _{cc}	Supply Current				18	30	mA

AC Electrical Characteristics (Note 6)

$I_{A} = 250$									
Symbol	Parameter	Conditions	Min	Тур	Мах	Units			
RS-422 CONNECTION, V _{cc} = 5V, MODE SELECT = 0.8V									
t _r	Output Rise Time	$R_{L} = 100\Omega, C_{L} = 500 \text{ pF} (Figure 1)$		120	200	ns			
t _f	Output Fall Time	$R_{L} = 100\Omega, C_{L} = 500 \text{ pF} (Figure 1)$		120	200	ns			
t _{PDH}	Output Propagation Delay	$R_{L} = 100\Omega, C_{L} = 500 \text{ pF} (Figure 1)$		120	200	ns			
t _{PDL}	Output Propagation Delay	$R_{L} = 100\Omega, C_{L} = 500 \text{ pF} (Figure 1)$		120	200	ns			
t _{PZL}	TRI-STATE Delay	$R_L = 450\Omega, C_L = 500 \text{ pF}, C_C = 0 \text{ pF} (Figure 4)$		250	350	ns			
t _{PZH}	TRI-STATE Delay	$R_L = 450\Omega, C_L = 500 \text{ pF}, C_C = 0 \text{ pF} (Figure 4)$		180	300	ns			
t _{PLZ}	TRI-STATE Delay	$R_L = 450\Omega$, $C_L = 500 \text{ pF}$, $C_C = 0 \text{ pF}$ (Figure 4)		180	300	ns			
t _{PHZ}	TRI-STATE Delay	$R_L = 450\Omega, C_L = 500 \text{ pF}, C_C = 0 \text{ pF} (Figure 4)$		250	350	ns			

DC Electrical Characteristics (Notes 3, 4, 5, 6)

Symbol	Parameter	Conc	litions	Min	Тур	Max	Units
RS-423 CON	NECTION, IV _{CC} I = IV _{EE} I, MODE §	SELECT ≥ 2V		•			
V _{IH}	High Level Input Voltage			2			V
V _{IL}	Low Level Input Voltage					0.8	V
I _{IH}	High Level Input Current	V _{IN} = 2.4V			1	40	μA
		$V_{IN} \le 15V$			10	100	μA
I _{IL}	Low Level Input Current	$V_{IN} = 0.4V$			-30	-200	μA
Vi	Input Clamp Voltage	$I_{IN} = -12 \text{ mA}$				-1.5	V
Vo	Output Voltage	R _L = ∞, (Note 7)	$V_{IN} = 2V$	4.0	4.4	6.0	V
$\overline{V_O}$		$V_{CC} \ge 4.75V$	$V_{IN} = 0.4V$	-4.0	-4.4	-6.0	V
V _T	Output Voltage	$R_L = 450\Omega$	V _{IN} = 2.4V	3.6	4.1		V
$\overline{V_T}$		$V_{CC} \ge 4.75V$	$V_{IN} = 0.4V$	-3.6	-4.1		V
$ V_T - \overline{V_T} $	Output Unbalance	$ V_{CC} = V_{EE} = 4.7$	5V, R _L = 450Ω		0.02	0.4	V
I _X +	Output Leakage Power OFF	$V_{CC} = V_{EE} = 0V$	$V_{\rm O} = 6V$		2	100	μA
I _X ⁻	Output Leakage Power OFF	$V_{CC} = V_{EE} = 0V$	$V_{\rm O} = -6V$		-2	-100	μA
I _S ⁺	Output Short Circuit Current	$V_{O} = 0V$	V _{IN} = 2.4V		-80	-150	mA
Is ⁻	Output Short Circuit Current	$V_{\rm O} = 0V$	$V_{IN} = 0.4V$		80	150	mA
I _{SLEW}	Slew Control Current				±140		μA
I _{cc}	Positive Supply Current	V _{IN} = 0.4V, R _L = ∞			18	30	mA
I _{EE}	Negative Supply Current	V _{IN} = 0.4V, R _L = ∞			-10	-22	mA

Note 2: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. They are not meant to imply that the devices should be operated at these limits. The tables of "Electrical Characteristics" provide conditions for actual device operation.

Note 3: Unless otherwise specified, min/max limits apply across the $-55^{\circ}C$ to $+125^{\circ}C$ temperature range for the DS1691A and across the 0°C to $+70^{\circ}C$ range for the DS3691. All typicals are given for V _{CC} = 5V and T_A = 25^{\circ}C. V_{CC} and V_{EE} as listed in operating conditions.

Note 4: All currents into device pins are positive; all currents out of device pins are negative. All voltages are referenced to ground unless otherwise specified. Note 5: Only one output at a time should be shorted.

Note 6: Symbols and definitions correspond to EIA RS-422 and/or RS-423 where applicable.

Note 7: At -55° C, the output voltage is +3.9V minimum and -3.9V minimum.

AC Electrical Characteristics (Note 6) $T_{4} = 25^{\circ}C$

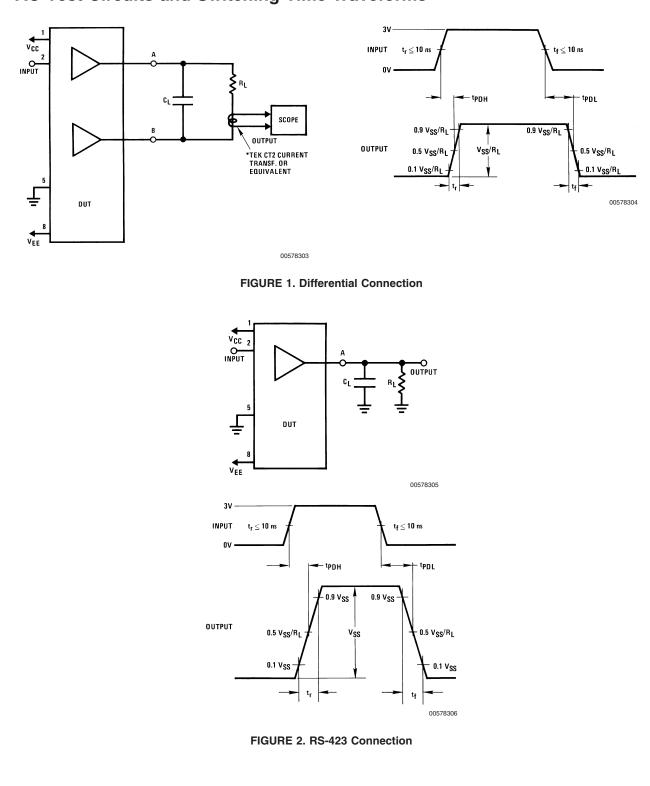
Symbol	Parameter	Conditions		Тур	Max	Units		
RS-423 CONNECTION, V _{CC} = 5V, V _{EE} –5V, MODE SELECT = 2.4V								
t _r	Rise Time	$R_L = 450\Omega$, $C_L = 500 \text{ pF}$, $C_C = 0$ (<i>Figure 2</i>)		120	300	ns		
t _f	Fall Time	$R_L = 450\Omega$, $C_L = 500$ pF, $C_C = 0$ (<i>Figure 2</i>)		120	300	ns		
t _r	Rise Time	$R_L = 450\Omega$, $C_L = 500 \text{ pF } C_C = 50 \text{ pF} (Figure 3)$		3.0		μs		
t _f	Fall Time	$R_L = 450\Omega$, $C_L = 500 \text{ pF } C_C = 50 \text{ pF} (Figure 3)$		3.0		μs		
t _{rc}	Rise Time Coefficient	$R_L = 450\Omega$, $C_L = 500 \text{ pF}$, $C_C = 50 \text{ pF}$ (<i>Figure 3</i>)		0.06		µs/pF		

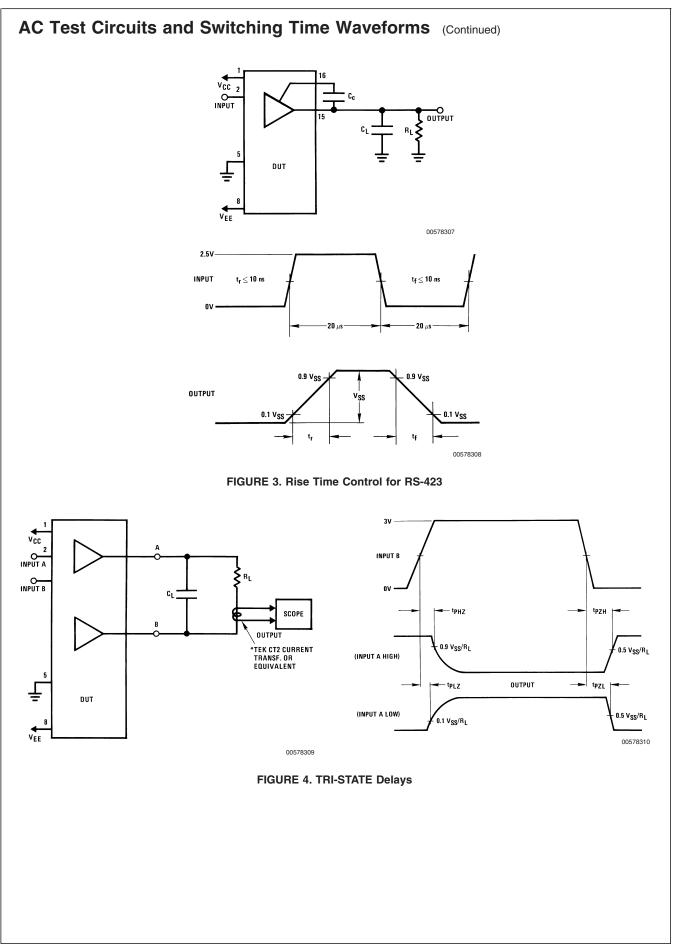
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AC Electrical Characteristics (Note 6) (Continued)

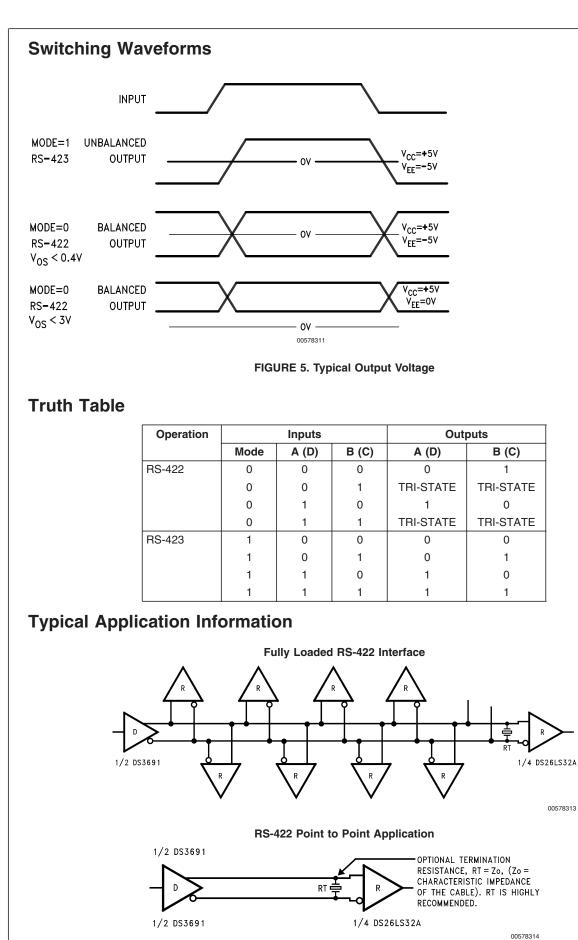
T _A = 25 C							
Symbol	Parameter	Conditions	Min	Тур	Max	Units	
t _{PDH}	Output Propagation Delay	$R_L = 450\Omega$, $C_L = 500 \text{ pF}$, $C_C = 0$ (<i>Figure 2</i>)		180	300	ns	
t _{PDL}	Output Propagation Delay	R_L = 450 $\Omega,~C_L$ = 500 pF, C_C = 0 (Figure 2)		180	300	ns	

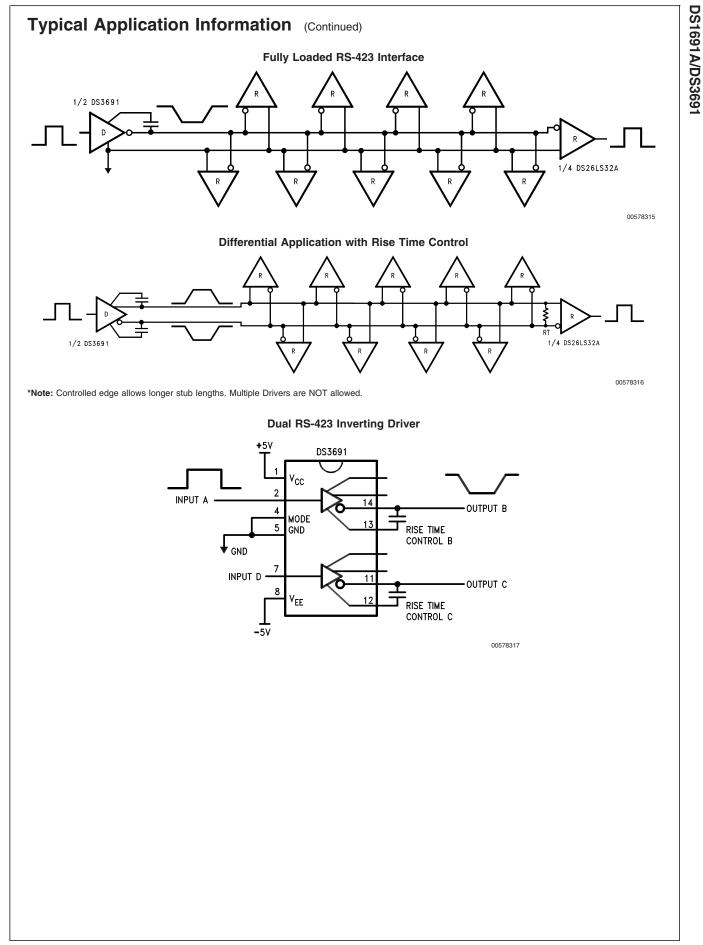
AC Test Circuits and Switching Time Waveforms





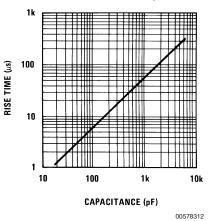


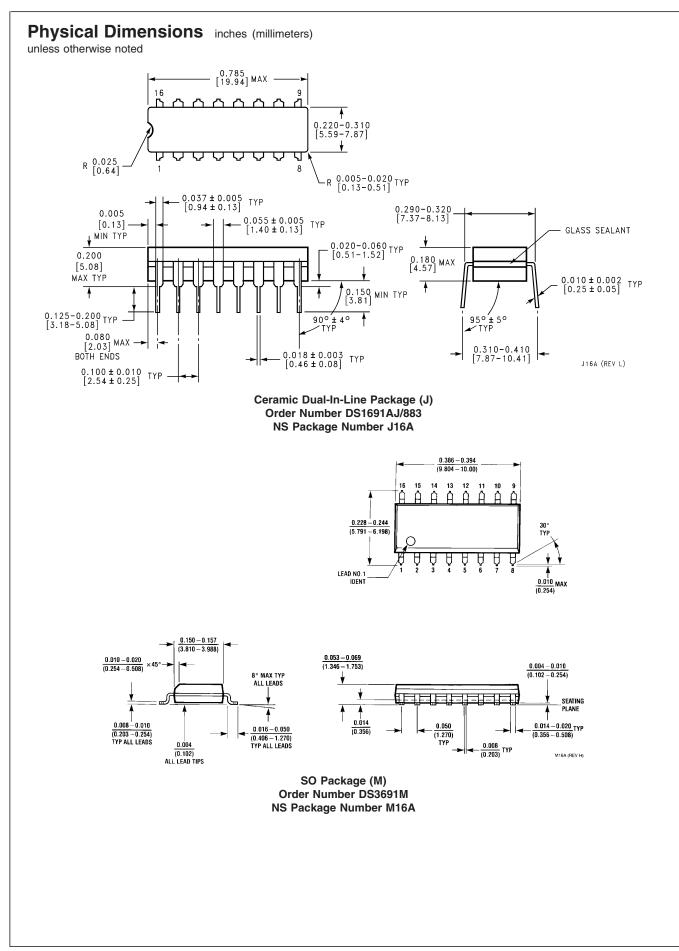


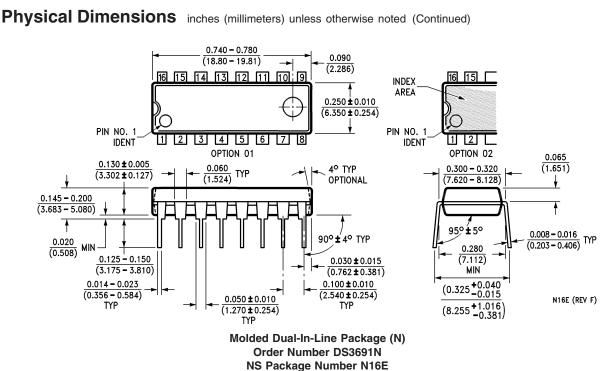


Typical Rise Time Control Characteristics (RS-423 Mode)

Rise Time vs External Capacitor







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